

## T498A685K004ZTE3K9

Obsolete

B45196P, Tantalum, MnO<sub>2</sub> Tantalum, High Temperature, 6.8 uF, 10%, 4 VDC, SMD, Molded, High Temperature, N/A, 3.9 Ohms, 3216, Height Max = 1.8mm



### General Information

Series	B45196P
Dielectric	MnO <sub>2</sub> Tantalum
Style	SMD Chip
Description	SMD, Molded, High Temperature
Features	High Temperature
RoHS	Yes
Termination	Tin
AEC-Q200	No
Notes	Obsolete. Old Part Number [Obsolete] Was B45196P0685K109.

### Specifications

Capacitance	6.8 uF
Capacitance Tolerance	10%
Voltage DC	4 VDC (85C), 3.19 VDC (125C), 2.68 VDC (150C)
Temperature Range	-55/+150°C
Rated Temperature	85°C
Dissipation Factor	4.5%
Failure Rate	N/A
Resistance	3.9 Ohms (100kHz)
Leakage Current	0.5 uA

### Dimensions

Footprint	3216
L	3.2mm +/-0.2mm
W	1.6mm +/-0.2mm
H	1.6mm +/-0.2mm
S	0.8mm +/-0.3mm
F	1.2mm +/-0.1mm
K	1.3mm TYP

### Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	2000